

Experimental study of different shaped nanopores in a porous silicon cathodic exchange membrane for reverse electrodialysis.

6^{ièmes} journées SemiConducteurs et Oxyde Poreux

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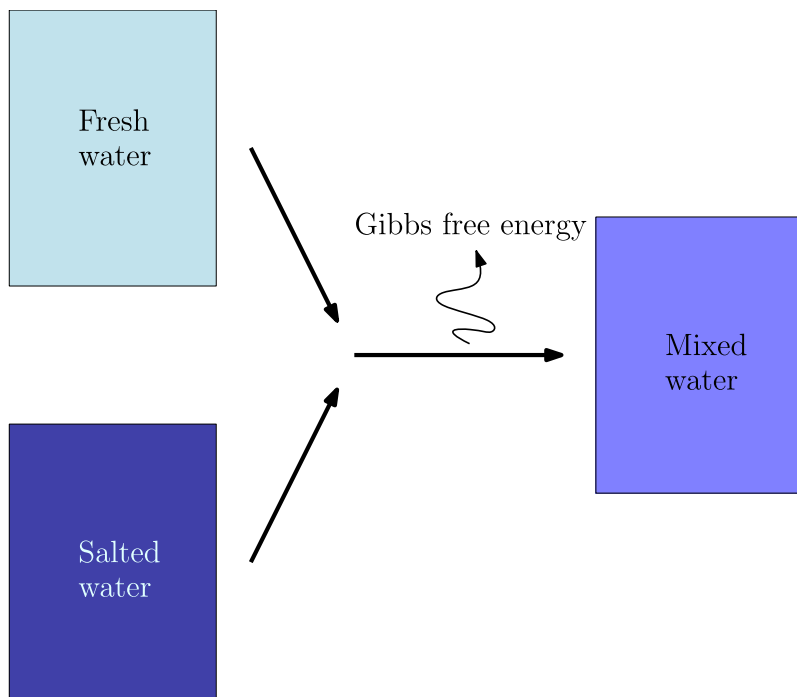
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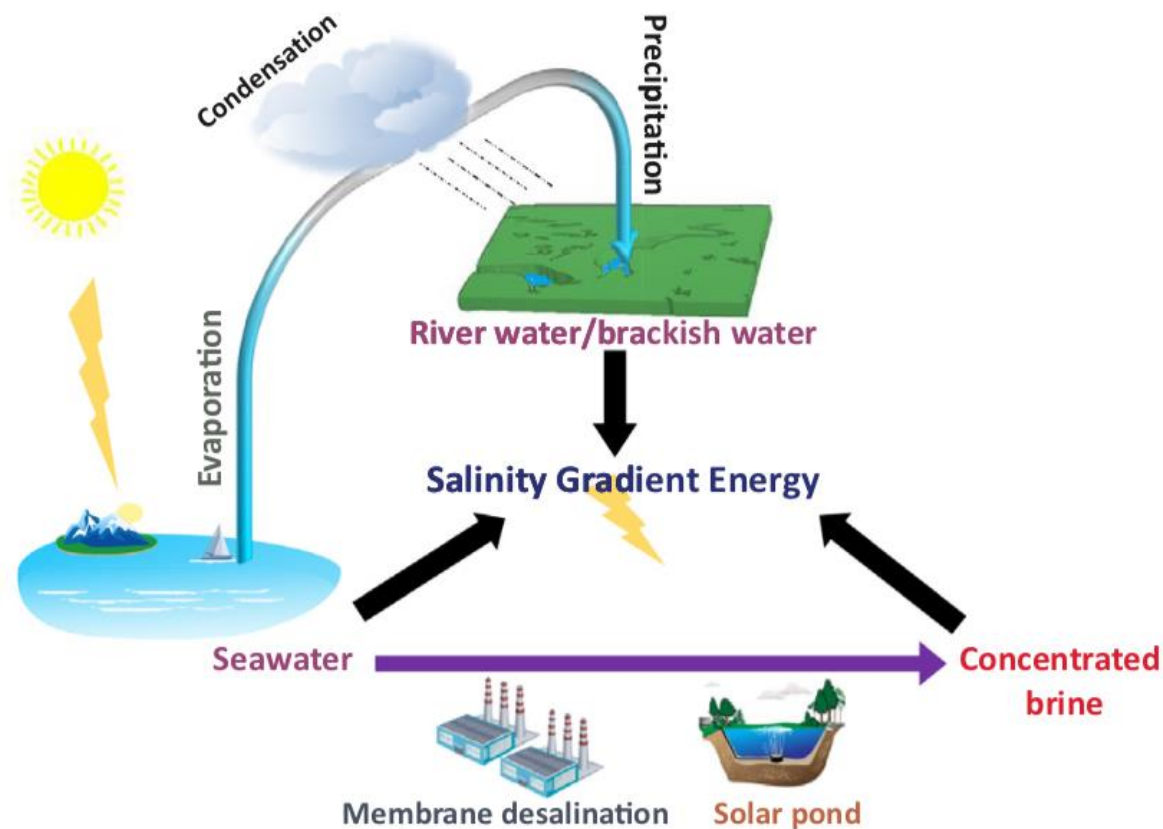
Louvain-La-Neuve (Belgium), November 9th and 10th, 2023

Blue energy



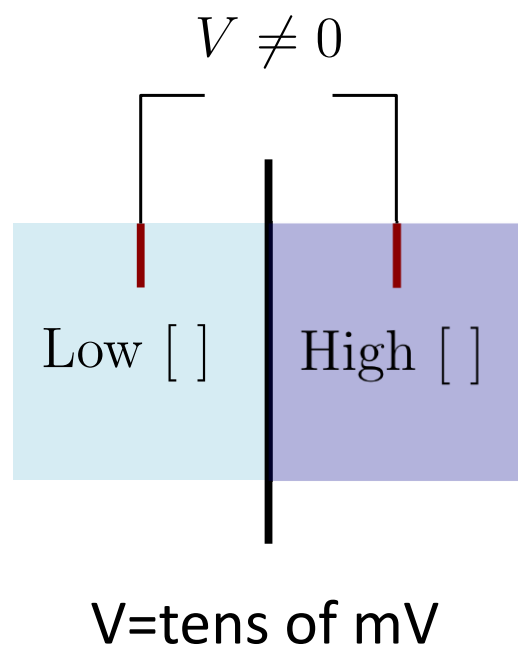
Large quantities available and renewable management possible

Theoretically: 1m^3 fresh water+ salted water \rightarrow 2.3 MJ of Gibbs free energy, continuously with no CO_2 production!



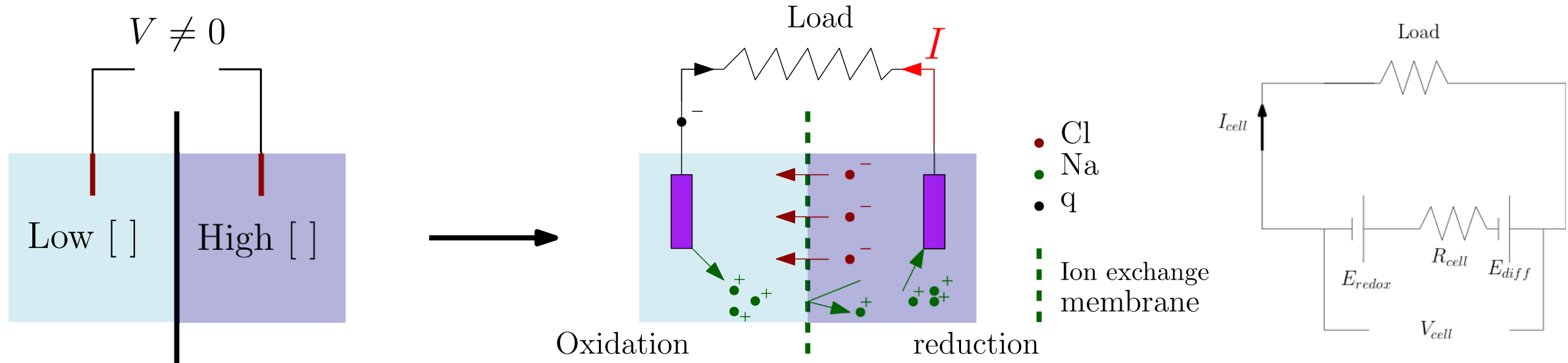
RED principle

- Reverse electrodialysis: harvesting blue energy (Gibbs Free energy)



RED principle

- Reverse electrodialysis: harvesting blue energy (Gibbs Free energy)



Technology based on ion selective membranes

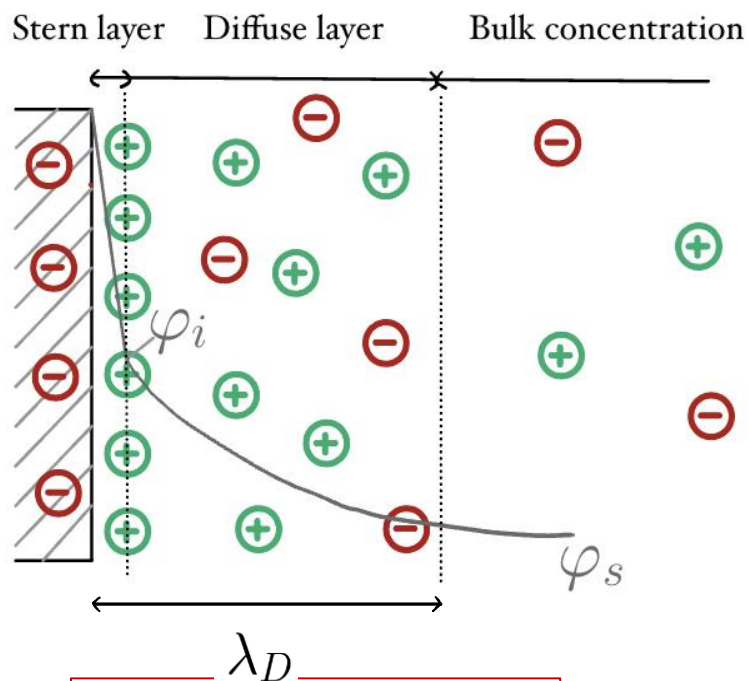
- High selectivity=high E_{diff}
- Low membrane ionic resistance=high I_{cell}

Porous silicon ion exchange membrane

Polymer based membrane	Inorganic Based membrane (Porous silicon)
Very selective	Generally less selective
Well known	Recent study
Adaptable	Topology controlable
Chemical degradation	Less chemical degradation
Less stable in time	More stable in time
	Easily integrable with CMOS

Selectivity through EDL overlap and Debye length

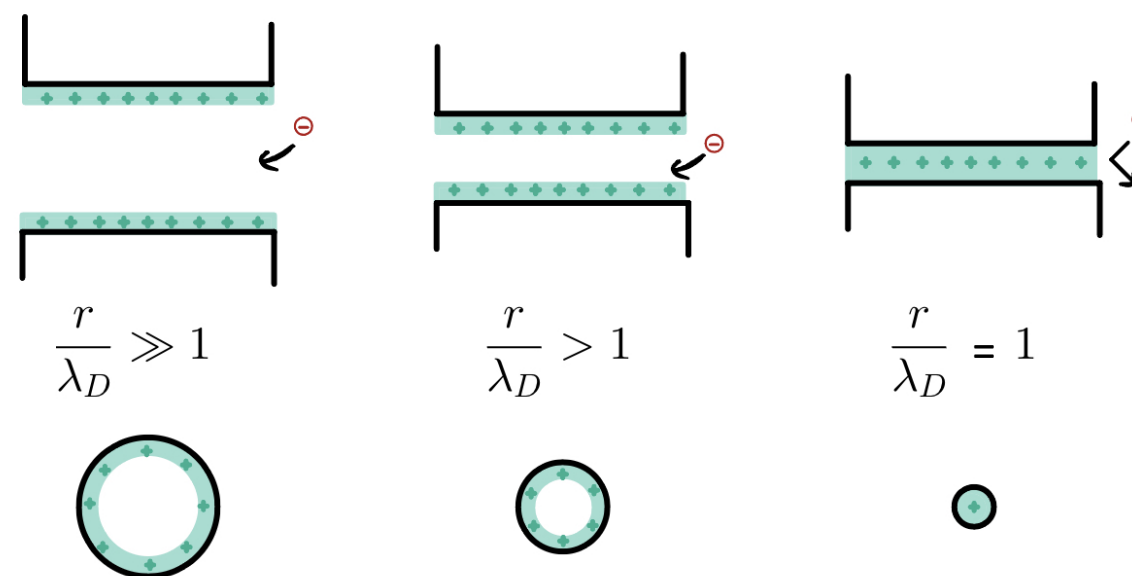
Electrical double layer (EDL)



$$\lambda_D \propto \sqrt{\frac{1}{C_i}}$$

- $C_i = 1\text{mM}$ \longrightarrow $\lambda_D \sim 10\text{ nm}$
- $C_i = 0.1\text{ mM}$ \longrightarrow $\lambda_D \sim 30\text{ nm}$

Electrical double layer overlap



Good selectivity with nanopores

Trade-off between selectivity and current

Radius ↗

➤ Selectivity ↘

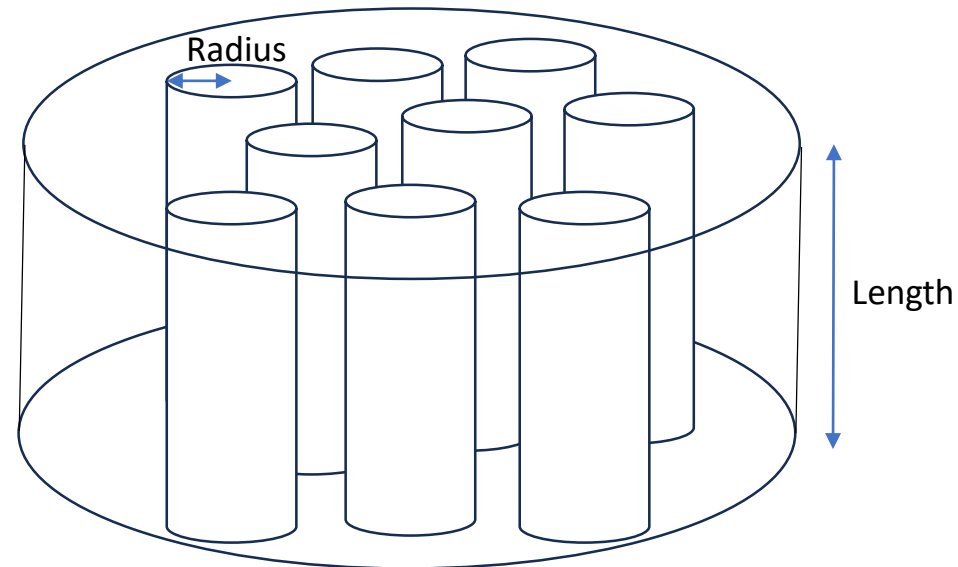
➤ R_{elec} ↘

➤ Ionic current ↗

Length ↗

➤ R_{elec} ↗

➤ R_{meca} ↗



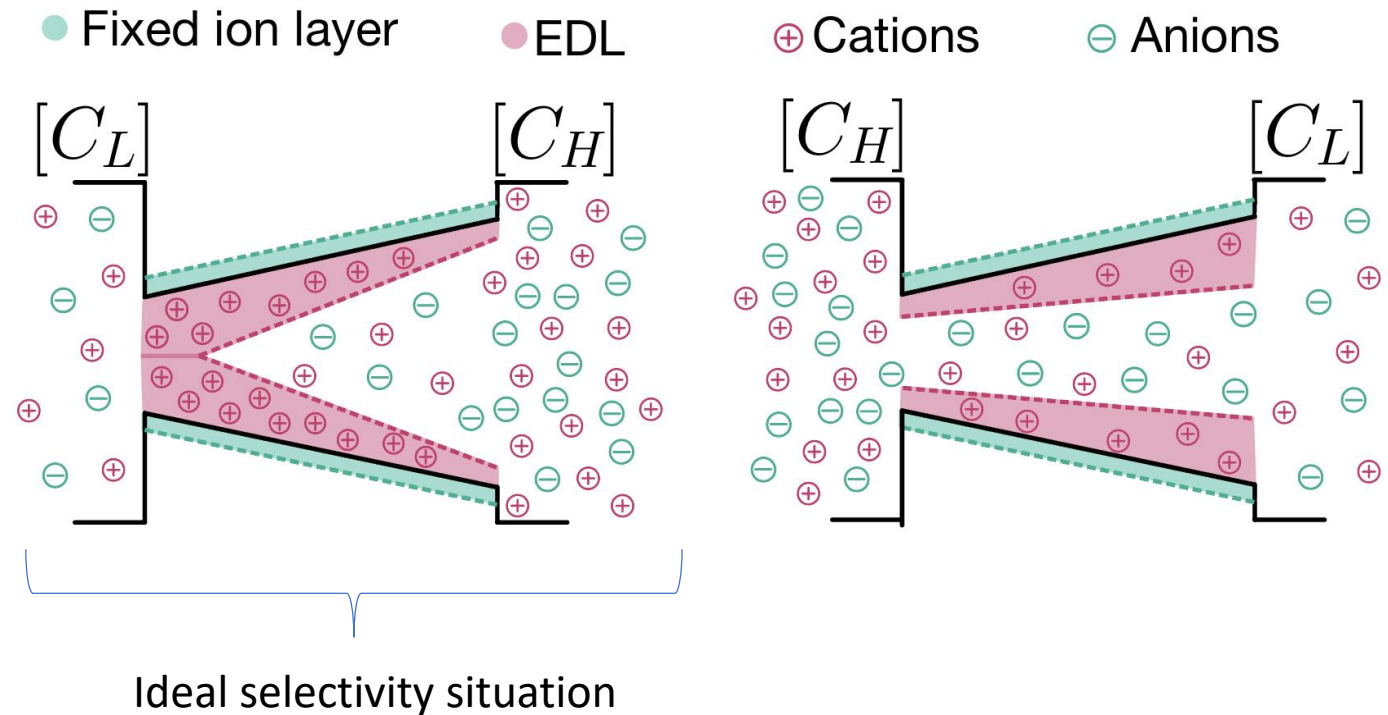
How to obtain selective, efficient and strong membranes?

Conical pores compared to smaller radius cylindrical pores

Potential of conical pores :

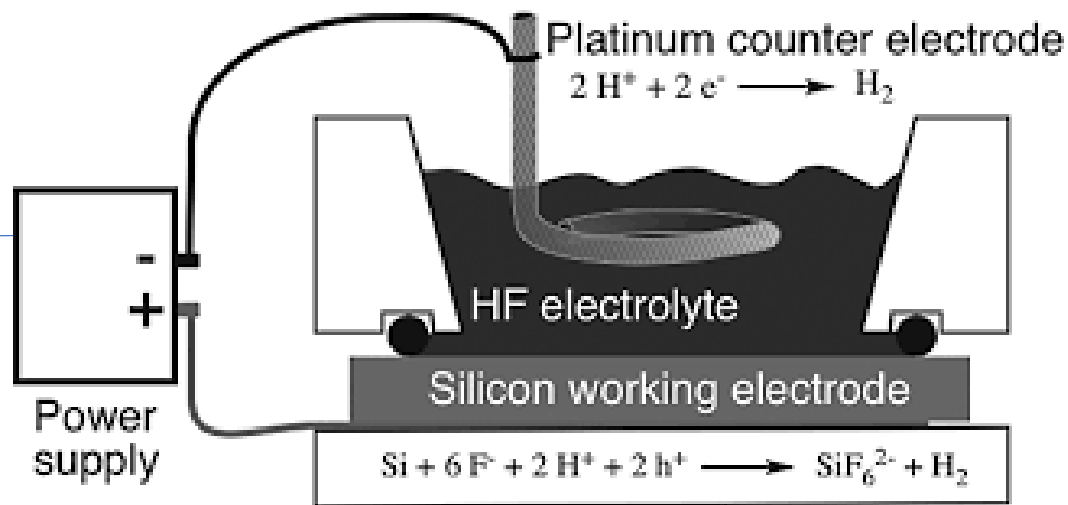
- Similar selectivity
- Higher ionic current
- Lower R_{elec}
- Weaker membrane

Theoretical asymmetry of EDL overlap:



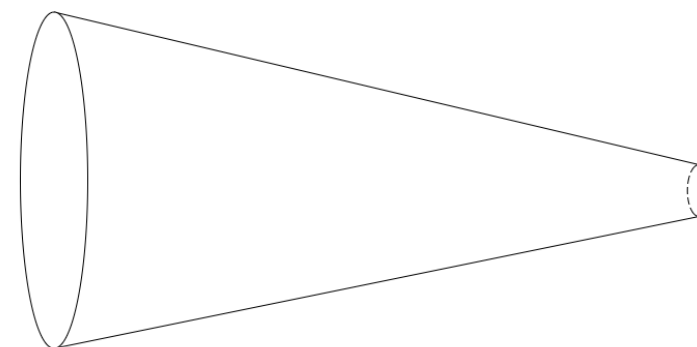
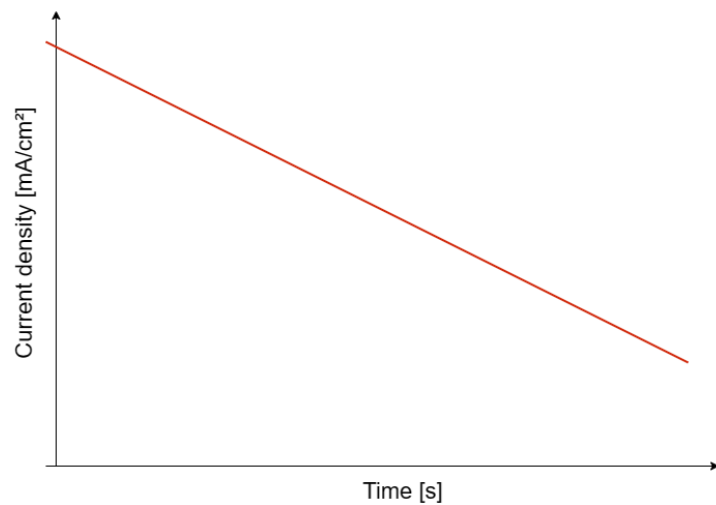
Fabrication of conical pores in porous silicon

Schematic of a two-electrode electrochemical cell [2]



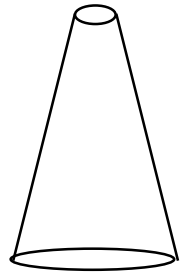
Influence of :

- Current density
 - Pore radius
 - Porosity
- Number of cycles
 - Membrane thickness

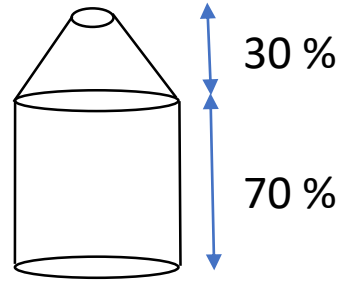


Conical shape pore

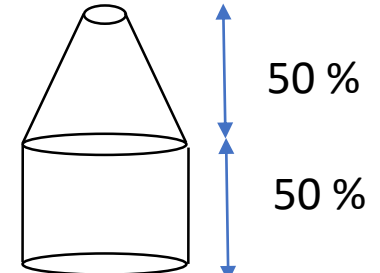
Main objective : study three different membrane topologies



CONICAL



PENCIL 70-30



PENCIL 50-50

Selectivity



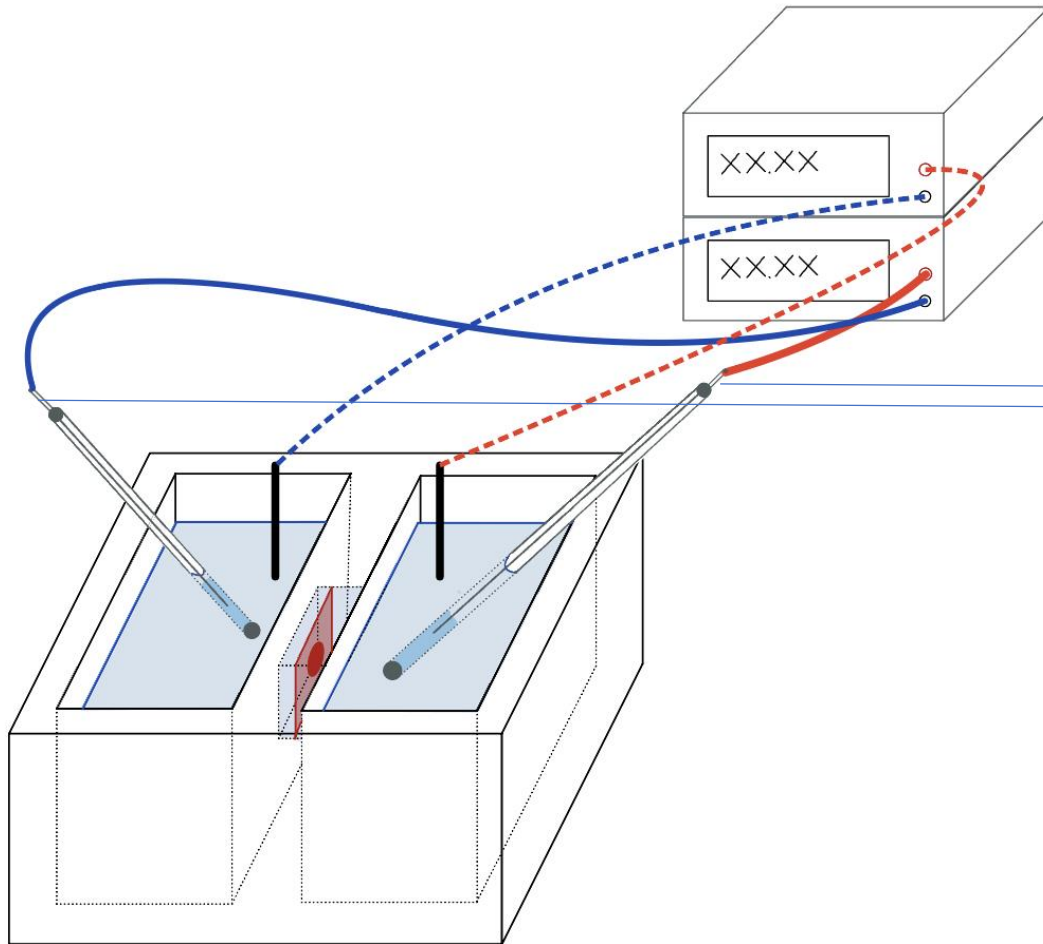
R_{elec}



R_{meca}

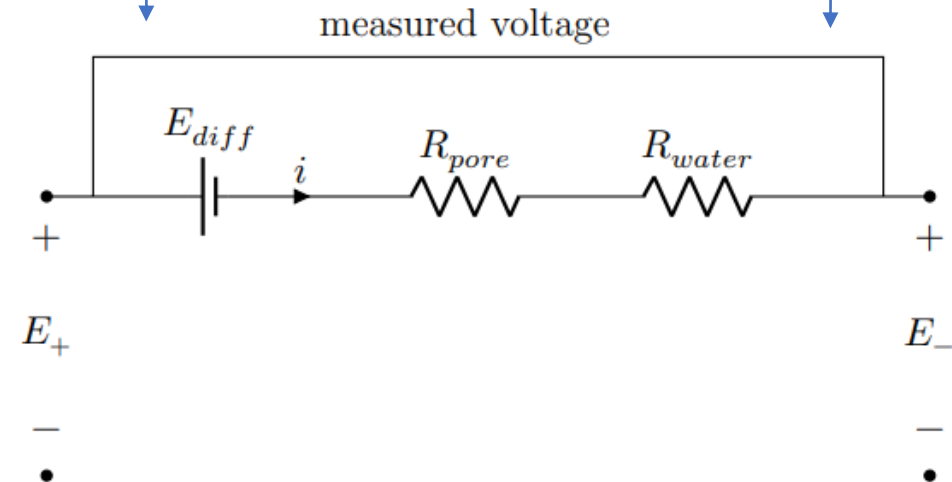


Experimental set-up

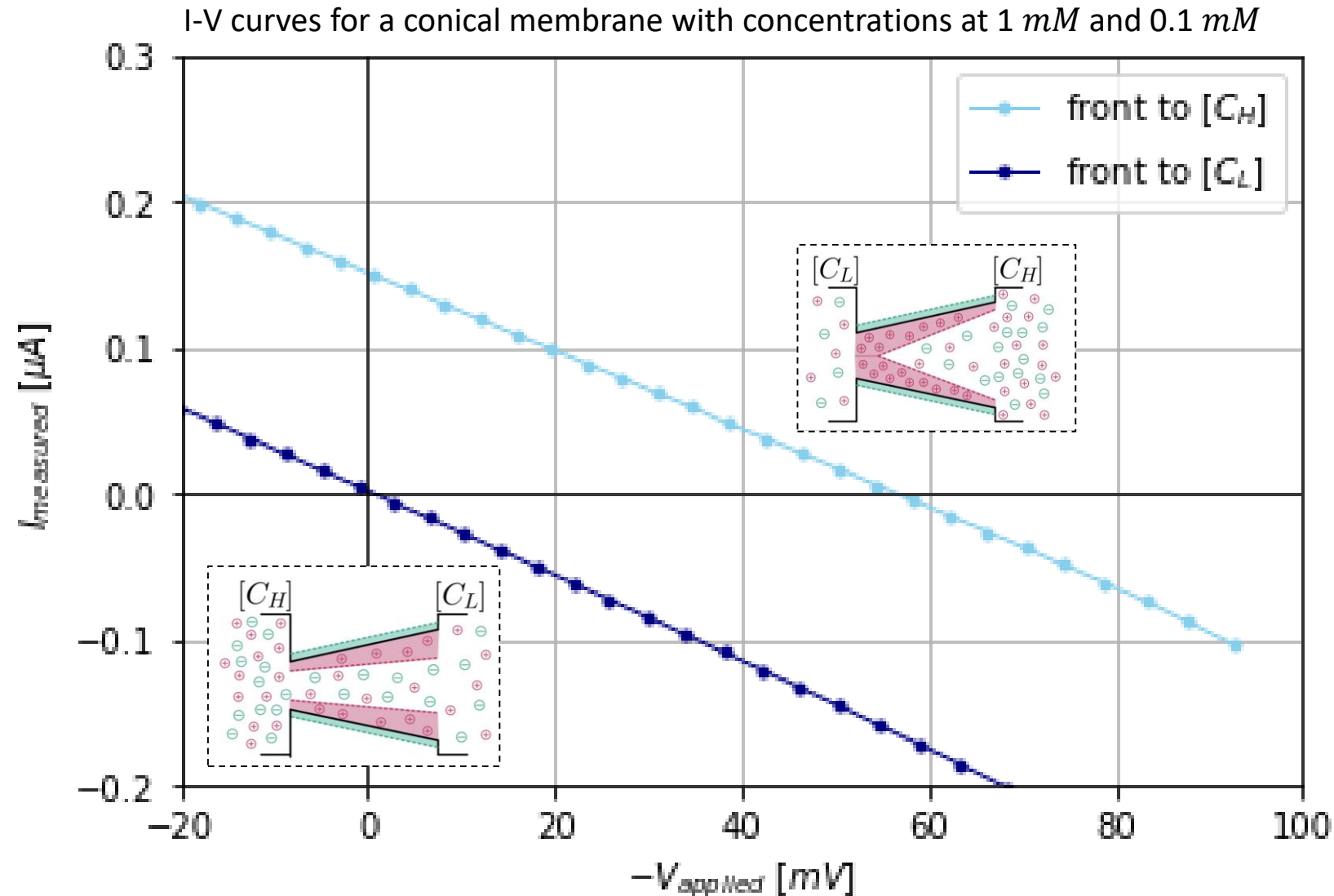


4 situations : 3 measures each

- 0.1 mM vs 1 mM : ideal
- 0.1 mM vs 1 mM : inverse
- 1 mM vs 10 mM : ideal
- 1 mM vs 10 mM : inverse

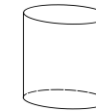
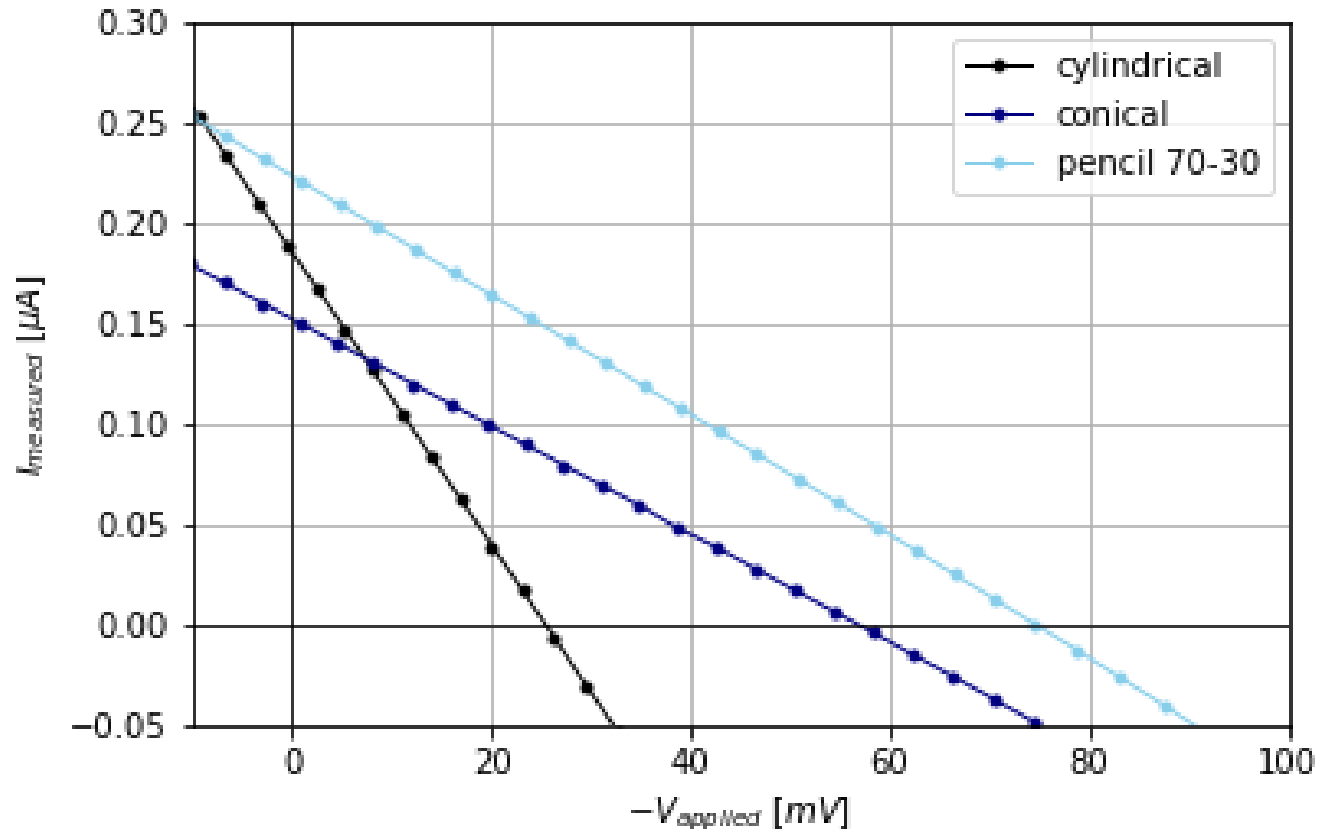


EDL overlap asymmetry



Topology impact : Maximal power density

Experimental results for different topologies



0.42 mW/m²



0.677 mW/m²



1.32 mW/m²

➤ $P_{\text{max,cyl}} < P_{\text{max,conic}} < P_{\text{max,pencil}}$

Important findings

PSi CEM
few mW/m²

CONICAL
Trade-off
selectivity-current

PENCIL
Best performance

Pore geometry is an effective parameter to improve RED efficiency

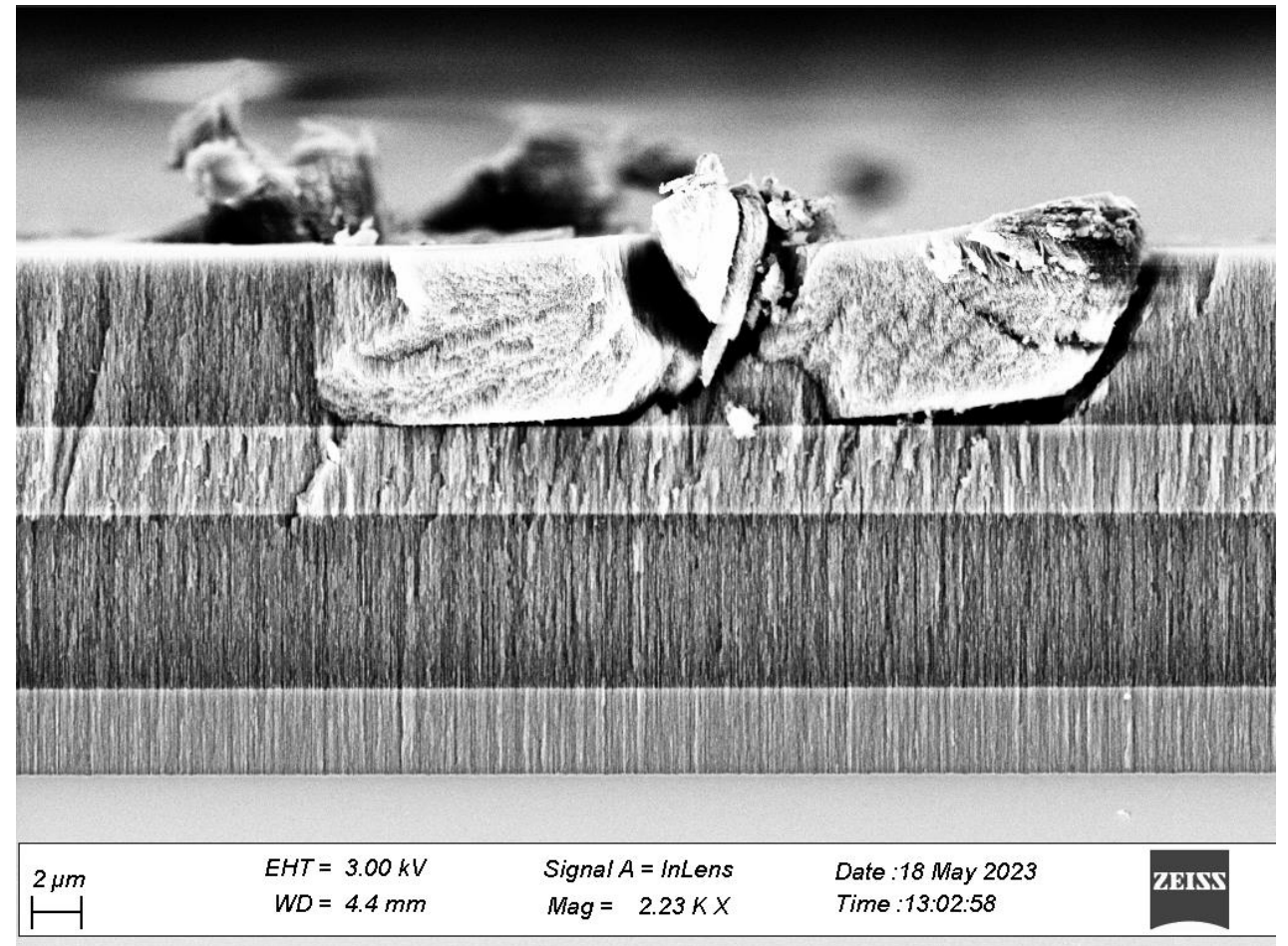
Futur works ideas

- Process of fabrication update
 - Porosification
 - Membrane release (DRIE)
- Surface charge density
 - Different material
 - Soft layer deposition [4]
 - Atomic layer deposition
- Other topologies

Futur works ideas

- Process of fabrication update
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Cross sectional view of stratified PSI



Thank you for your attention !
Any questions ?

PSi CEM
few mW/m²

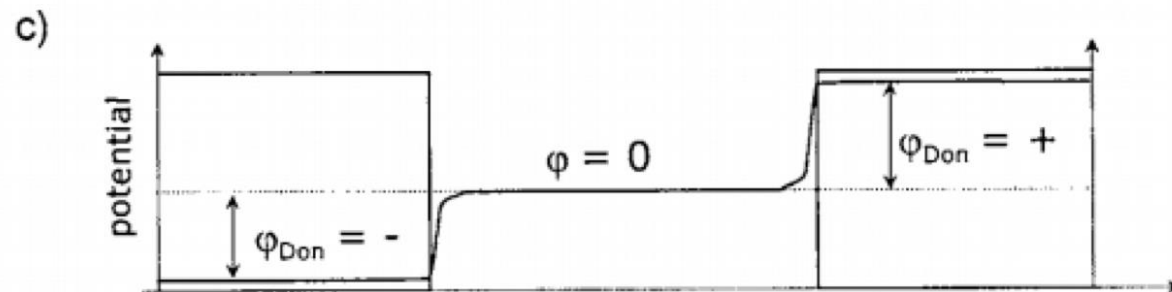
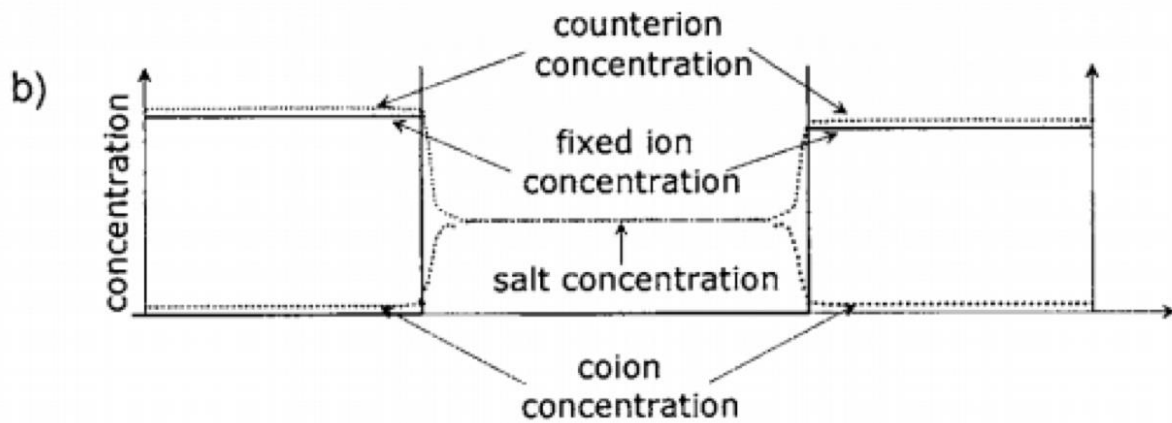
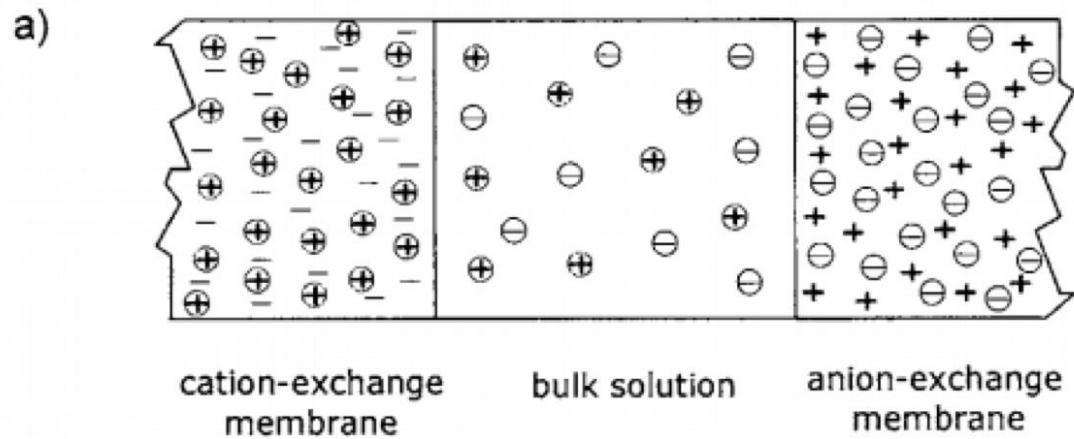
CONICAL
Trade-off
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Best performance

Pore geometry is an effective parameter to improve RED efficiency

Bibliography

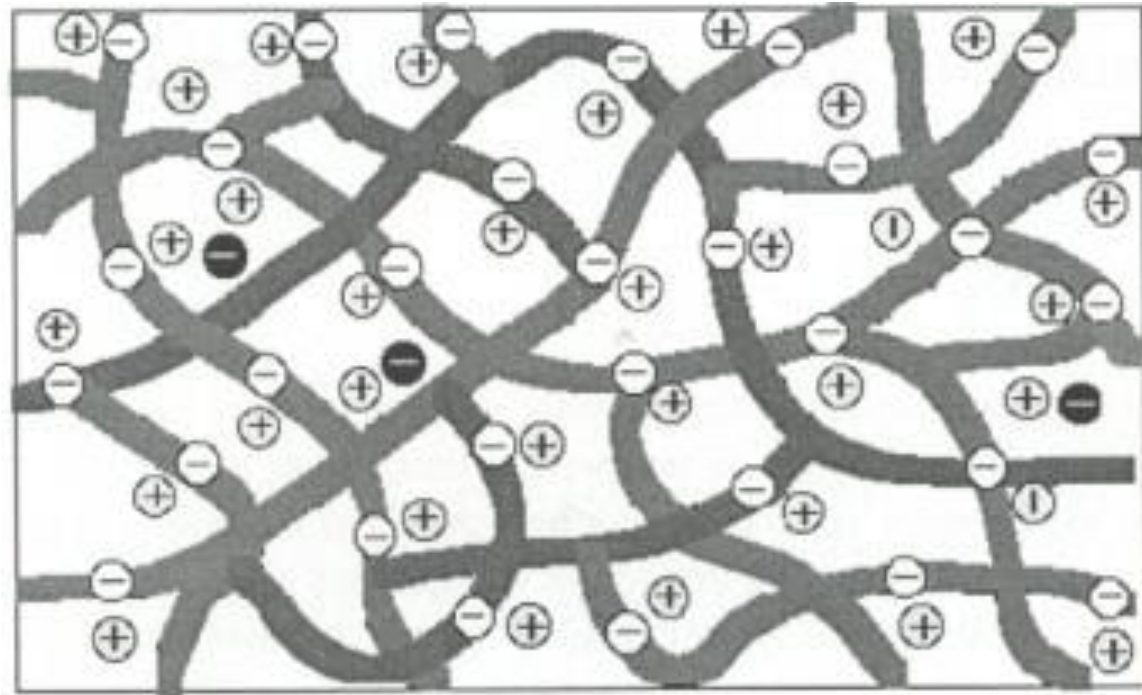
- [1] R. Hanus, “Harvesting blue energy using porous silicon,” Ph.D. dissertation, Ecole polytechnique de Louvain, Université catholique de Louvain, 2019.
- [2] M. J. Sailor, *Porous Silicon in Practice*. Wiley, 2011
- [3] G. Scheen, “Metal electrode integration and palladium nanoparticle functionalization on a miniaturized macroporous silicon chemiresistor,” Ph.D. dissertation, Ecole polytechnique de Louvain, Université catholique de Louvain, 2015
- [4] H. Dartoomi, M. Khatibi, and S. N. Ashrafizadeh, “Importance of nanochannels shape on blue energy generation in soft nanochannels,” *Electrochimica Acta*, vol. 431, p. 141175, 2022. [Online]. Available: <https://www.sciencedirect.com/science/article/pii/S0013468622013329>



Membrane potential

Polymer

Amount of counterion attached adaptable

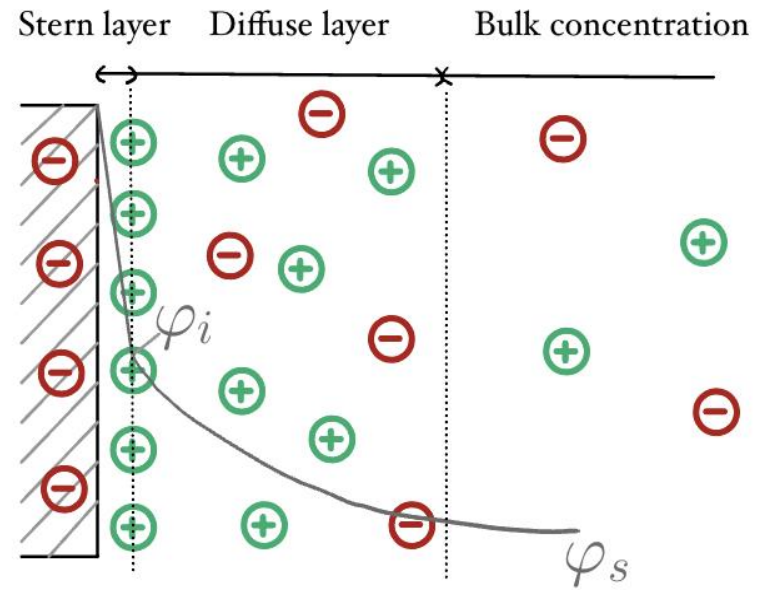


⊖ fixed ion ⊕ counterion ● coion

~ polymer matrix

PSi

Amount of counterion liberated depends on EDL



Commercial IEM

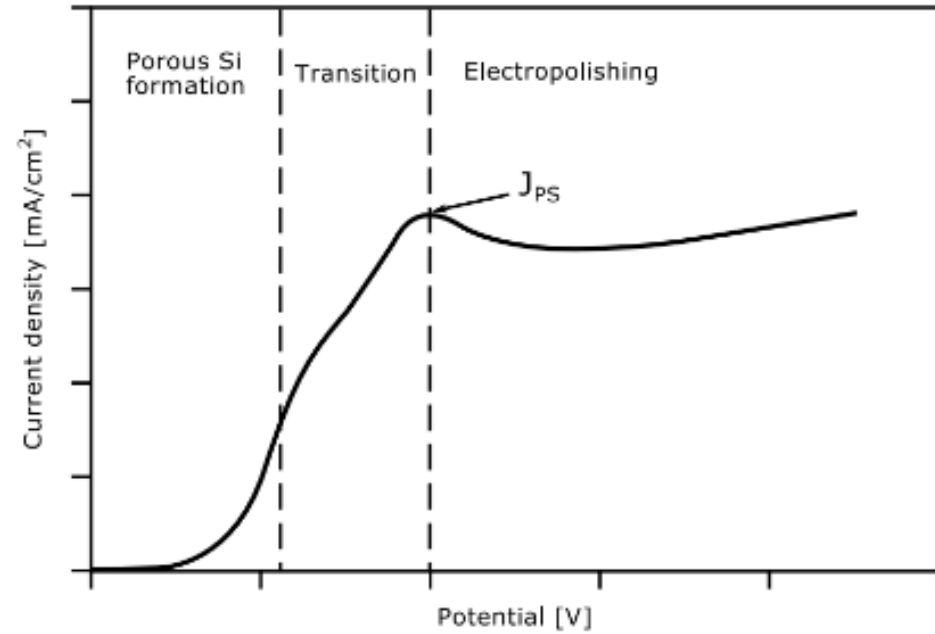
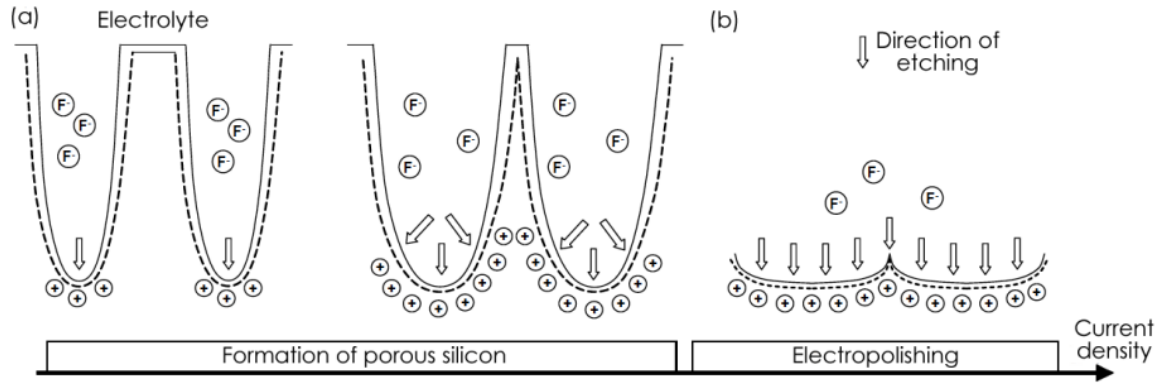
- Power : 0.3-4 W/m²
- Selectivity : Up to 99%

PSi cylindrical IEM

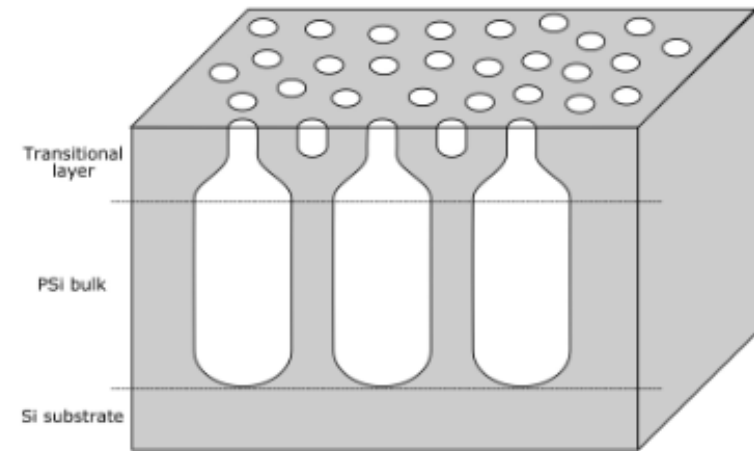
- Power : ~ 0.3 W/m²
- Selectivity : 60-70%

Pore parameters influence

Increasing of	Selectivity	Resistance	Current
Length of the pore	Decrease	Increase	Decrease
Radius of the pore	Increase	Decrease	Increase
Surface charge density	-	-	Increase
Concentration ratio	-	Increase	Increase
Concentration	Decrease	Decrease	Increase

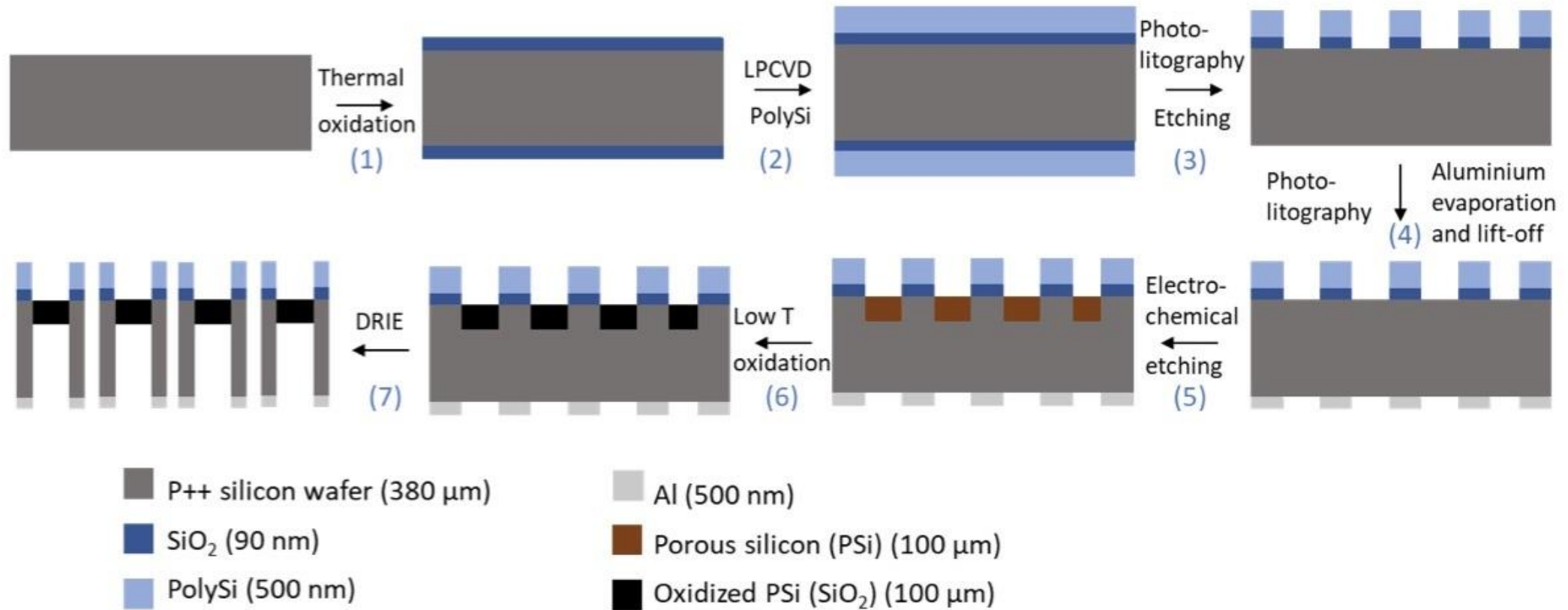


Increase of	Porosity	Etching rate	Critical current
HF concentration	Decreases	Decreases	Increases
Current density	Increases	Increases	-
Anodization time	Increases	Almost constant	-
Temperature	-	-	Increases
Wafer doping (p-type)	Decreases	Increases	Increases
Wafer doping (n-type)	Increases	Increases	-

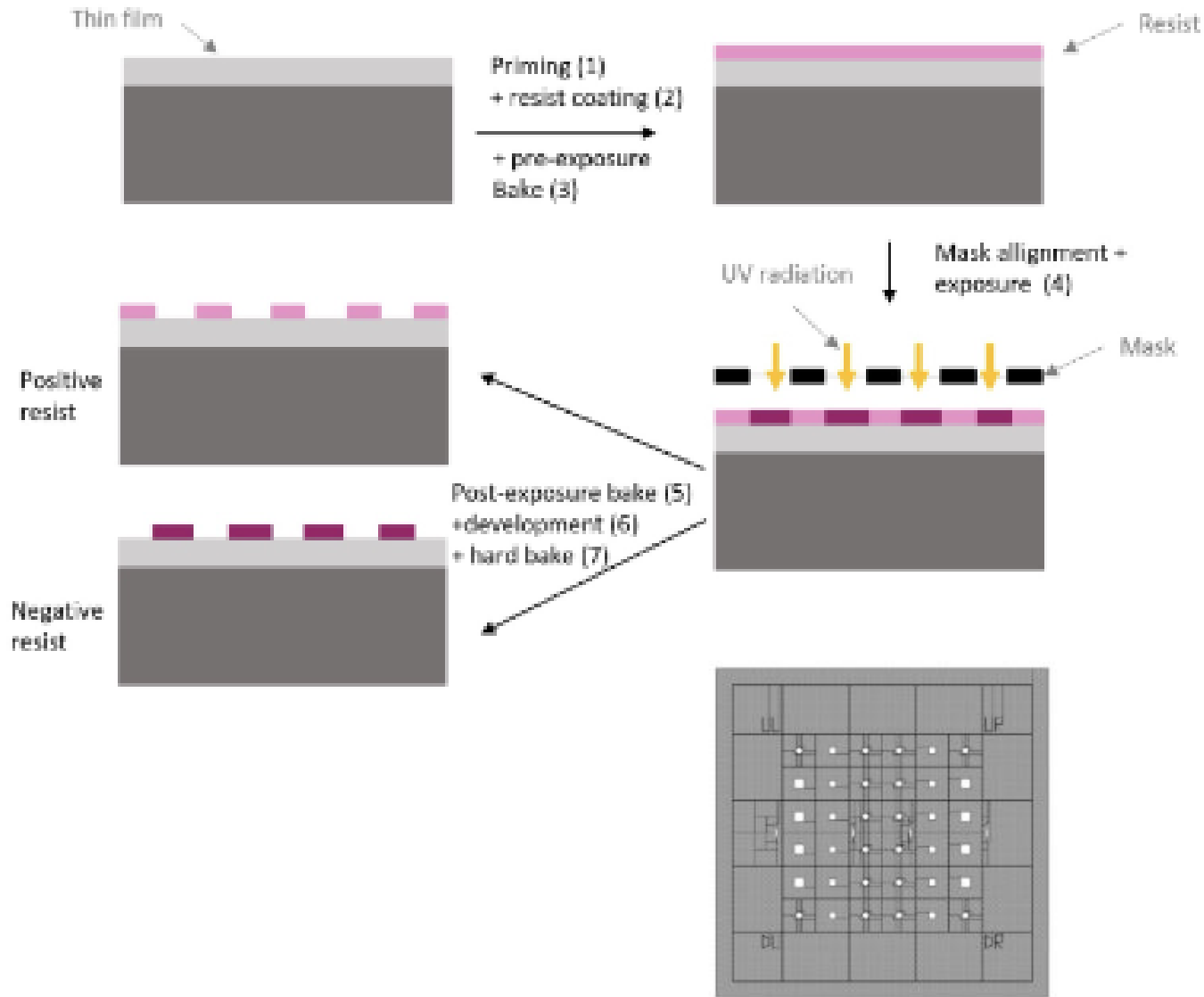


- Substrate: Si p++ boron, 0.8-0.9m Ω.cm
- Current density range: 100mA/cm² → 20mA/cm²

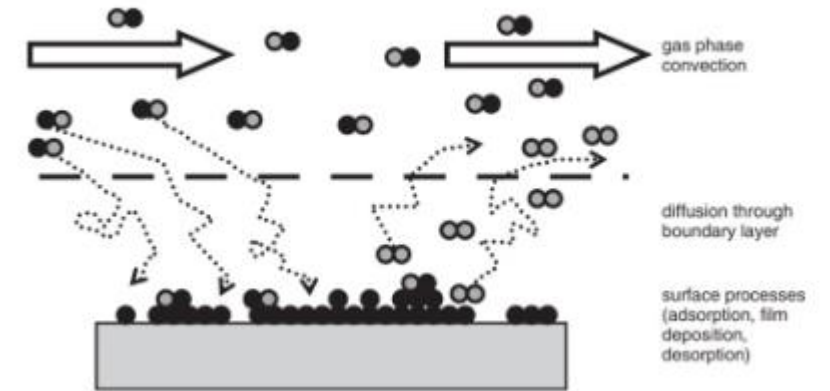
Additional support : process



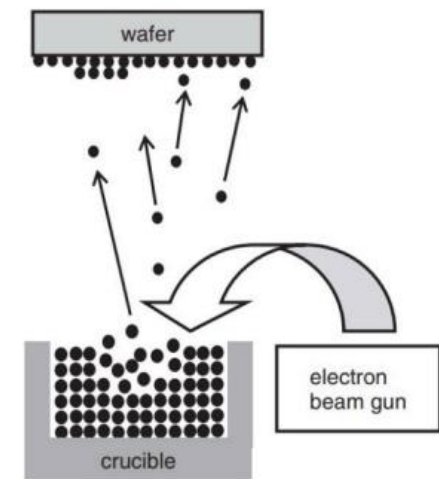
Lithographie



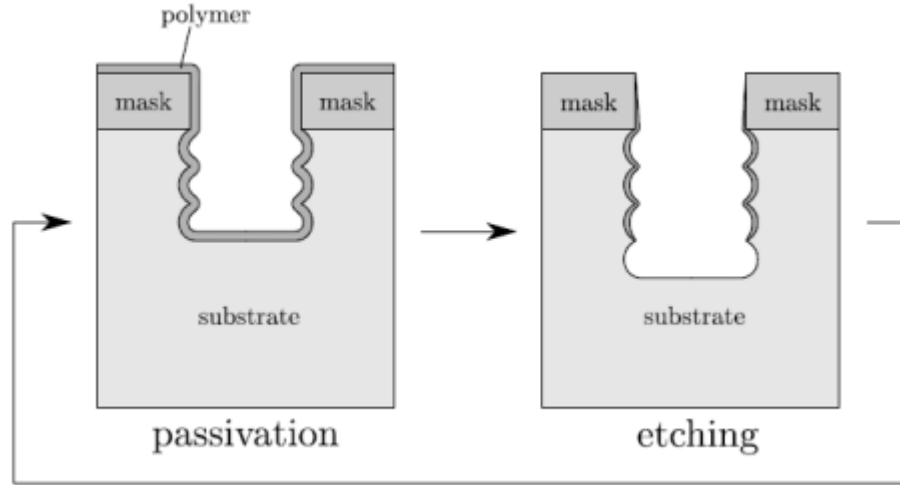
LPCVD



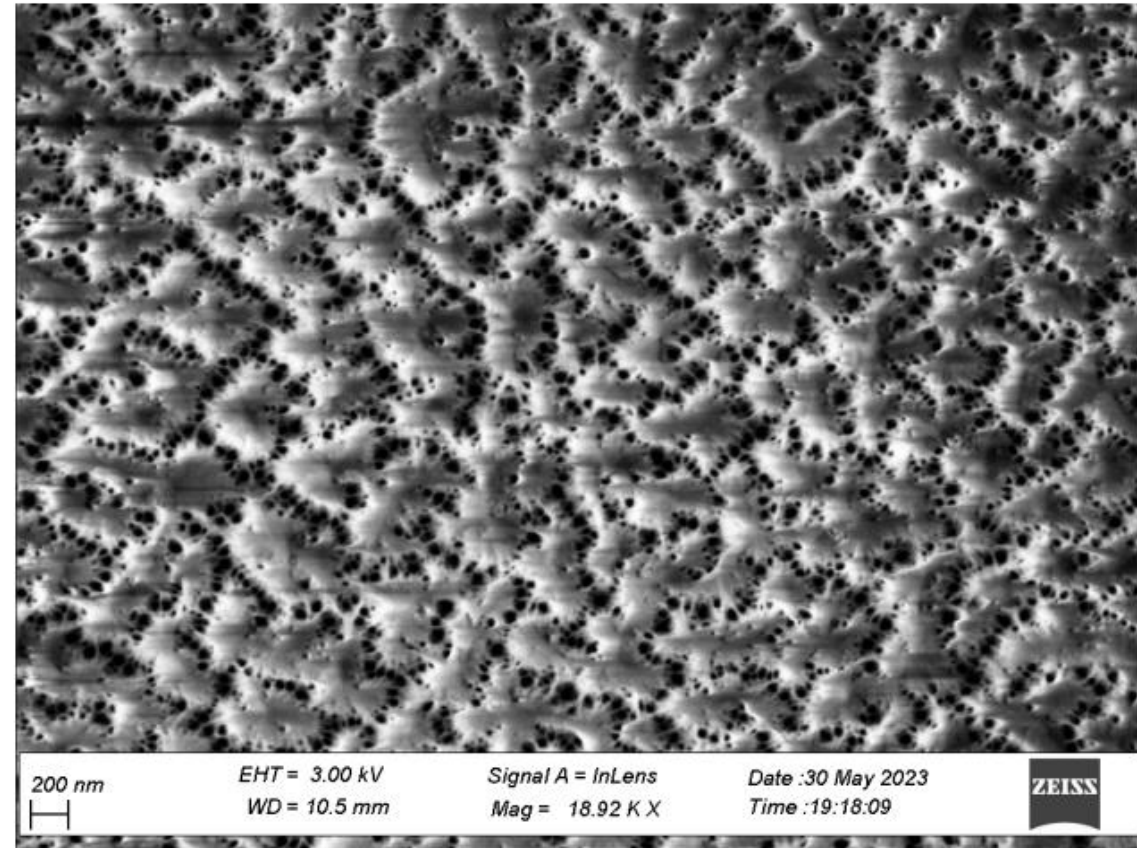
Alu e-beam



DRIE



	Etching	Passivation
Duration	13s	6s
SF_6 flow	120sccm	1sccm
C_4F_8 flow	1sccm	150 sccm
RF power	30W	10W
ICP power	1500 W	1500 W
Temperature	-10°C	-10°C
Pressure	20mTorr	20mTorr



Rectification Diffusion coefficient

- Nernst potential : 1 ion

$$E_{redox} = \frac{RT}{zF} \ln\left(\frac{\gamma_H C_H}{\gamma_L C_L}\right) (1-2t_+)$$

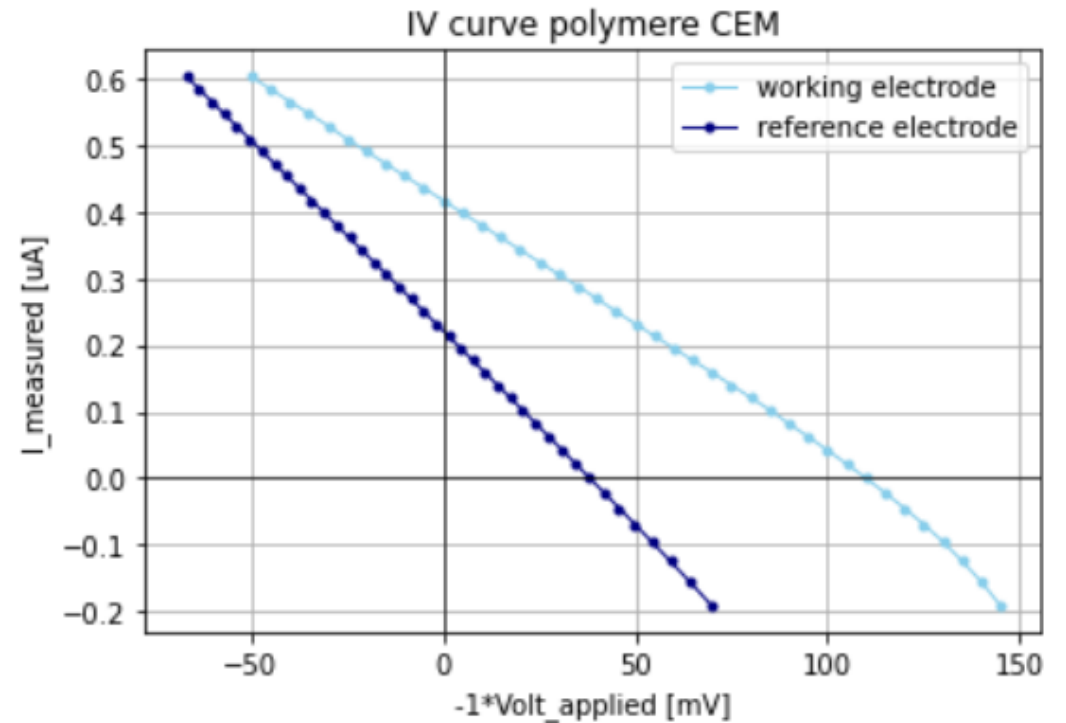
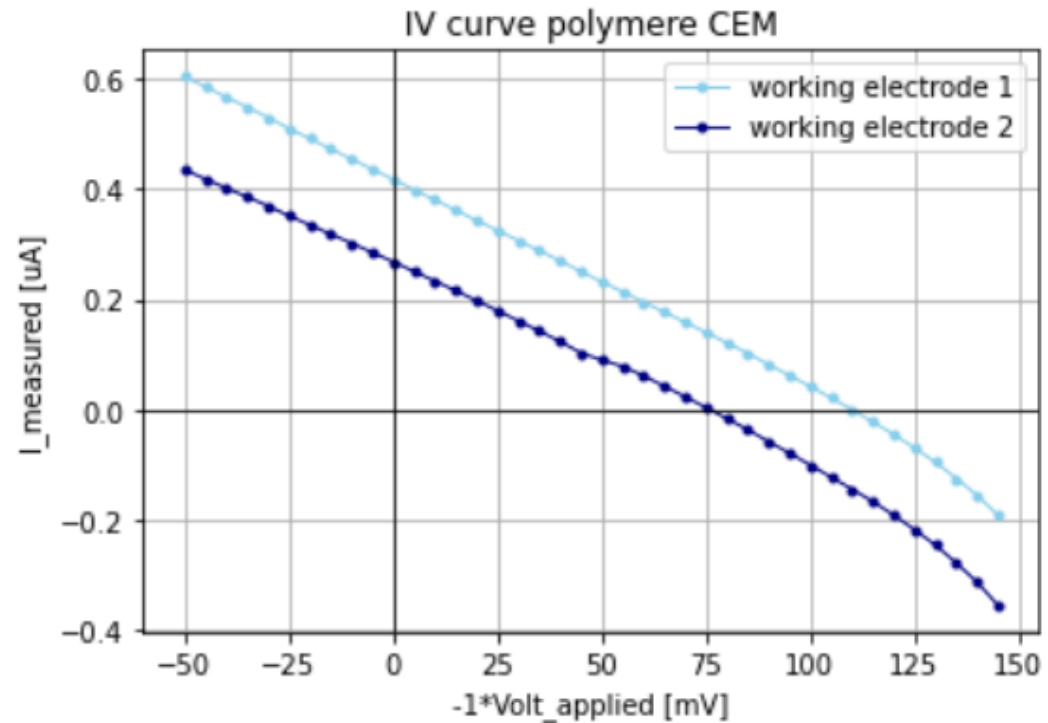
- Nernst modified : 2 ions

$$E_{redox} = \frac{RT}{zF} \ln\left(\frac{\gamma_H C_H}{\gamma_L C_L}\right) \left(1-2t_+ + \frac{D_{Cl^-} - D_{Na^+}}{D_{Cl^-} + D_{Na^+}}\right)$$

- Constant field equation : As many ions but need of permselectivity

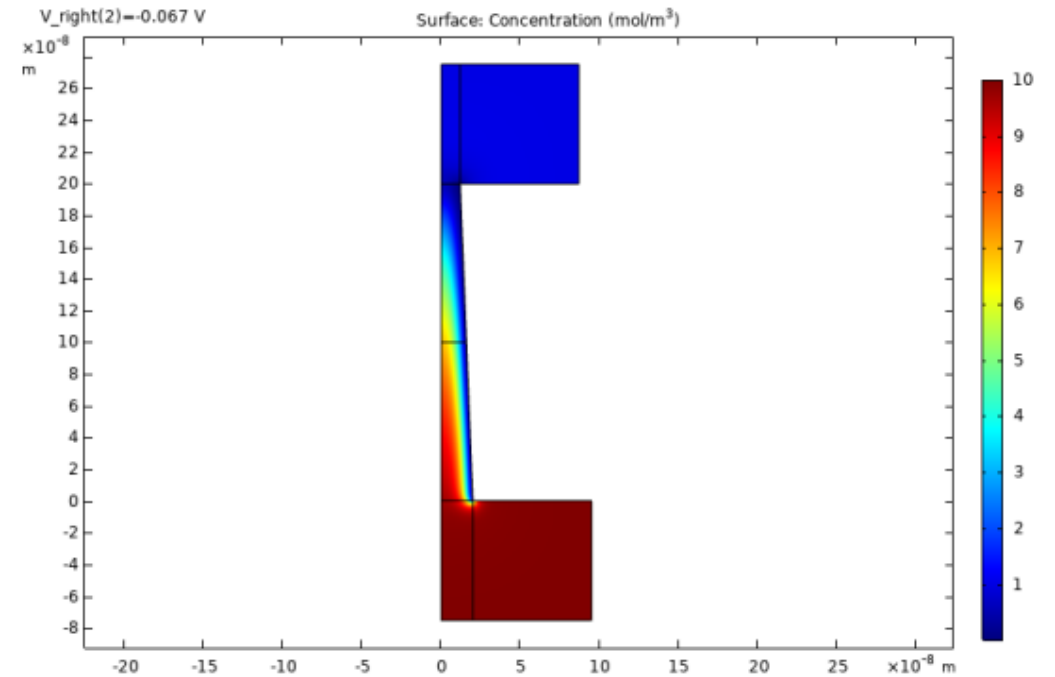
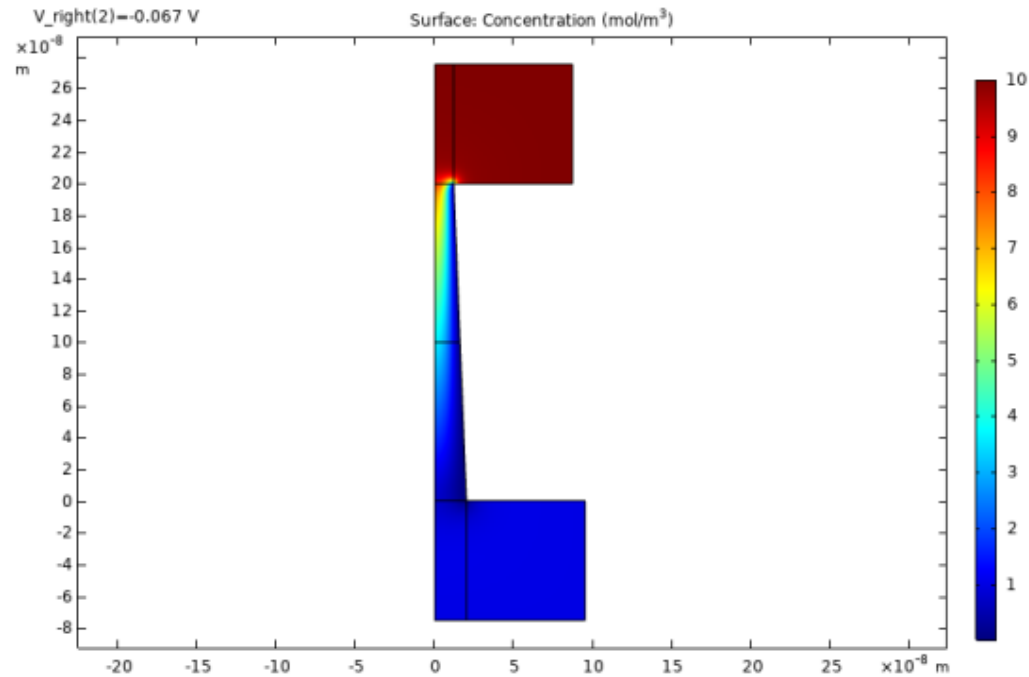
$$E_m = \frac{RT}{F} \ln \left(\frac{\sum_i^n P_{M_i^+} [M_i^+]_{out} + \sum_j^m P_{A_j^-} [A_j^-]_{in}}{\sum_i^n P_{M_i^+} [M_i^+]_{in} + \sum_j^m P_{A_j^-} [A_j^-]_{out}} \right)$$

Reference electrode



Standard deviation : 1 mV, 15 nA

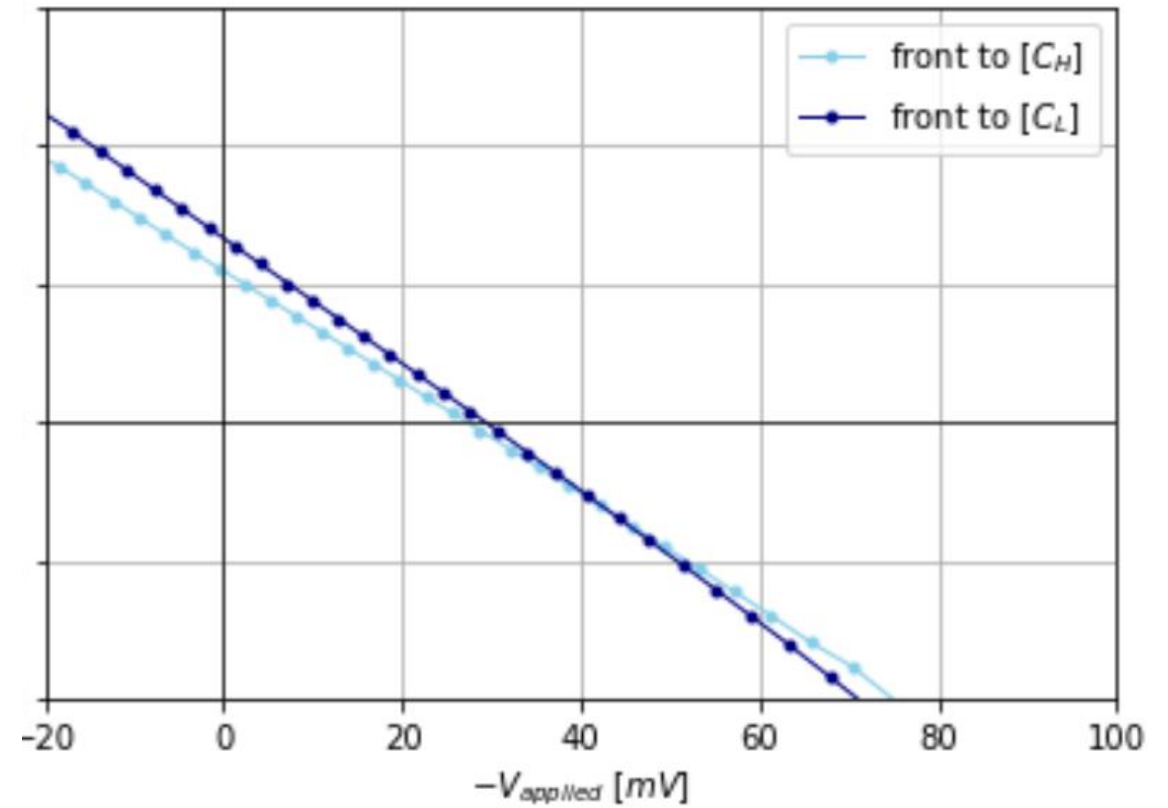
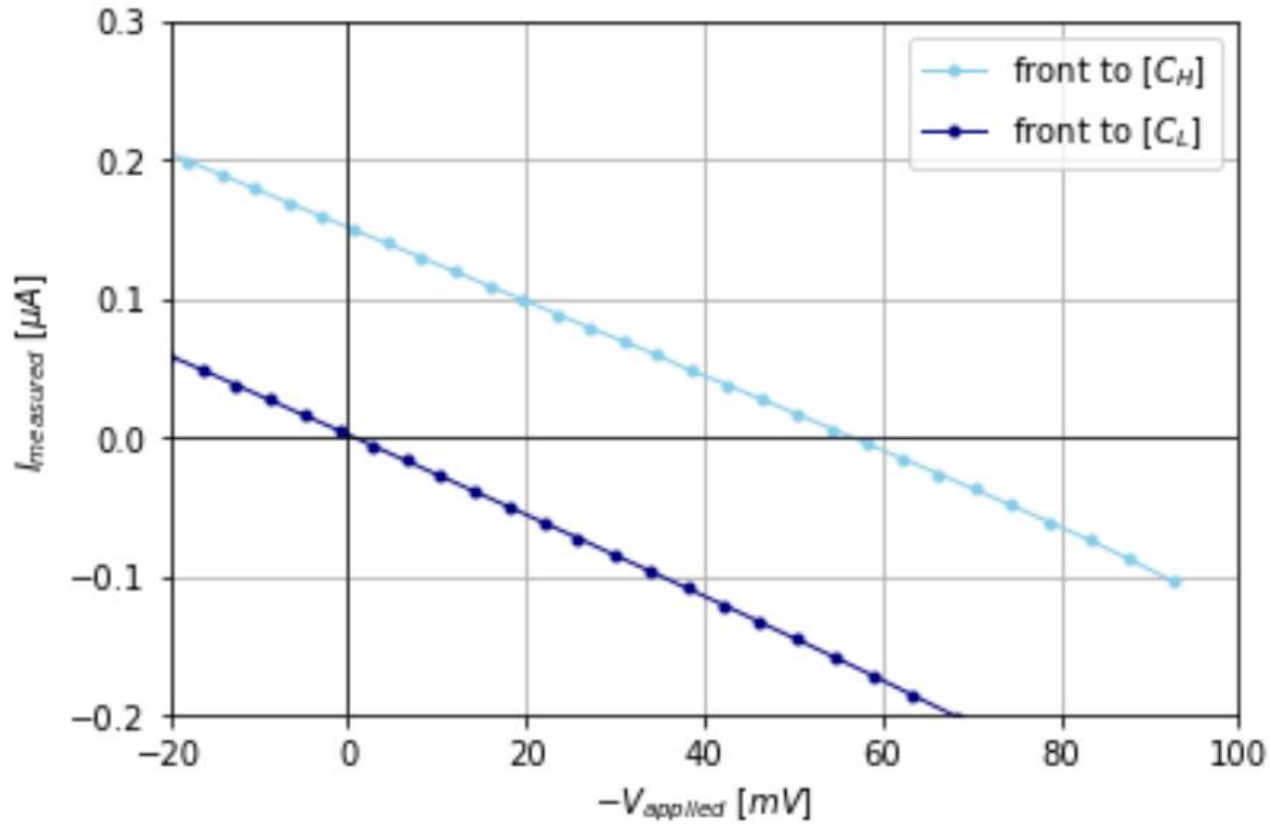
Concentration of anion in mol/m³
Blue = flow mainly due to cation = selectivity



Choice of parameter in single layer

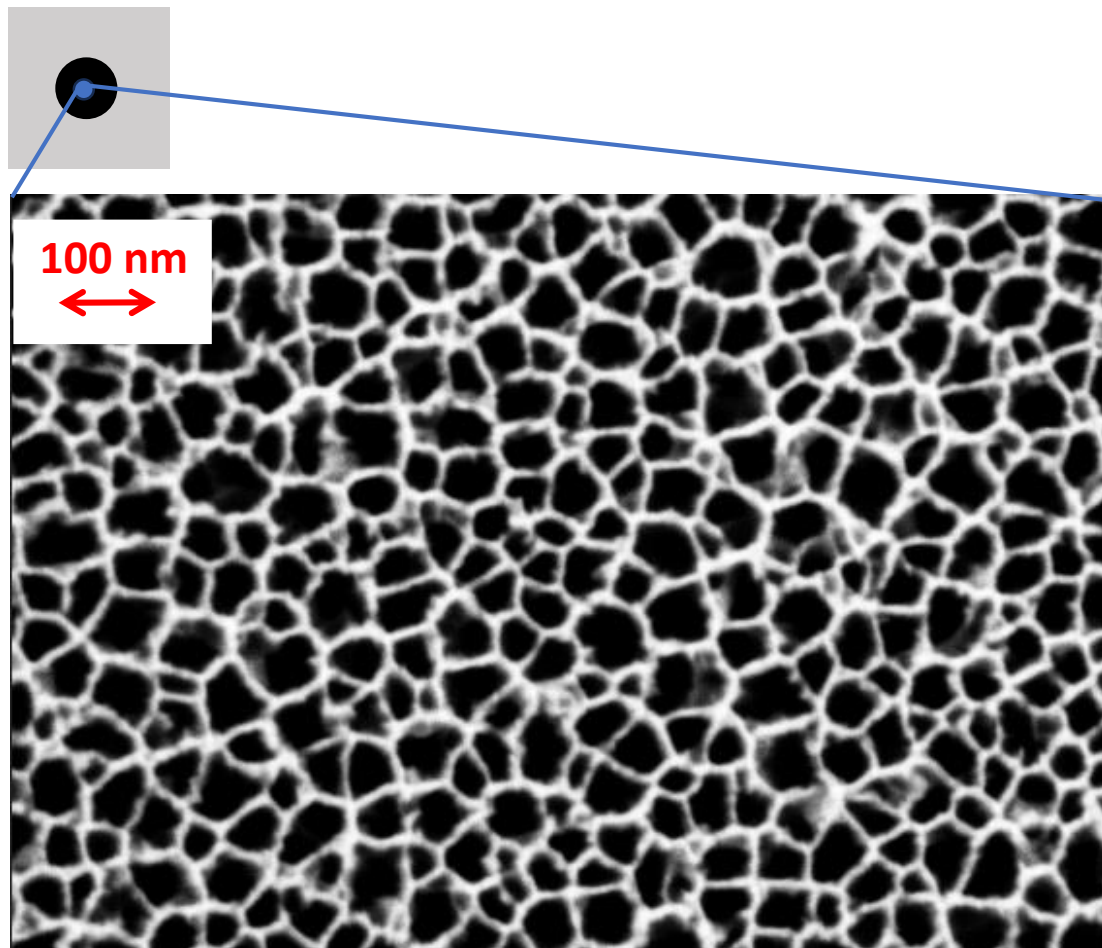
- The minimal current density is set to 20 mA/cm^2 to ensure the proper thickness of the PSi. This density corresponds to a diameter of 15 nm which is sufficient to obtain the EDL overlap as the Debye length is around $10\text{-}20 \text{ nm}$.
- The maximal current density is set to 100 mA/cm^2 to avoid detachment problems and electropolishing. This density corresponds to a diameter of 40 nm .
- The number of cycles depends directly on the script used as explained previously.
- The thickness is set to $50 \text{ }\mu\text{m}$. As explained in section 4.1.3, the electrical resistance of the channel is proportional to its length. Additionally, detachment and cracks were more frequently observed for longer pores.

Concentration impact

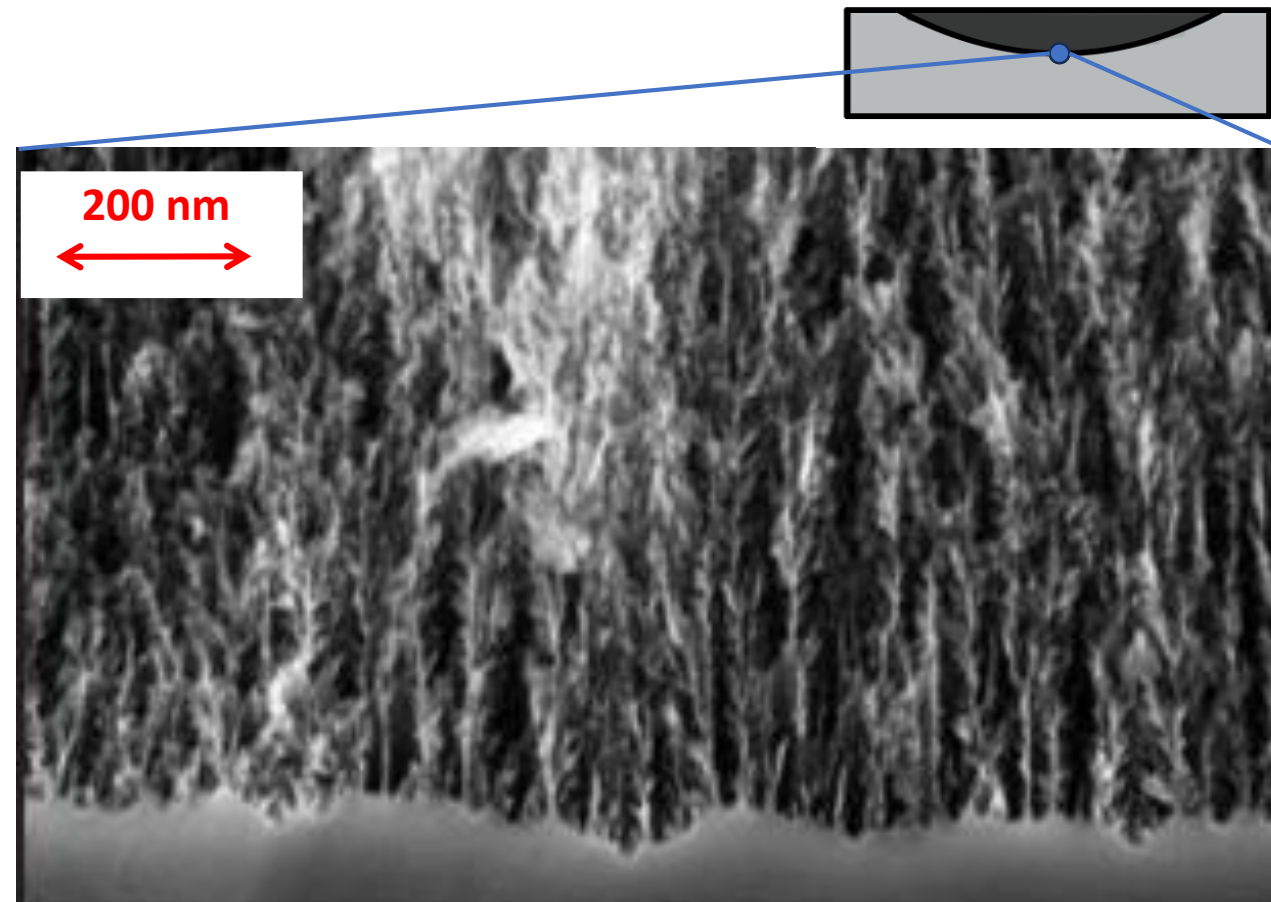


Summary results

Membrane	C_H & C_L	$E_{\text{diff}}[mV]$	σ_{OCV}	$I[\mu A]$	σ_I	$R_{\text{cell}}[k\Omega]$	$P[mW/m^2]$	$t_+[-]$
cylindrical	1 & 0.1 mM	-35.48	3.66	0.149	0.014	248.402	0.355	0.94
	10 & 1 mM	-11.43	0.26	0.338	0.012	33.568	0.246	0.716
conical	1 & 0.1 mM	-79.23	2.15	0.26	0.011	320.65	1.8	1.34
	10 & 1 mM	-23.87	0.94	0.503	0.019	47.177	0.96	0.83
pencil 70-30	1 & 0.1 mM	-80.152	10.94	0.259	0.04	317.18	1.55	1.35
	10 & 1 mM	-51.545	2.54	0.985	0.026	52.27	3.6	1.087
pencil 50-50	1 & 0.1 mM	-43.79	14.7	0.1435	0.045	299.73	0.475	1.015
	10 & 1 mM	6.11	0.85	0.281	0.046	21.762	0.136	0.55



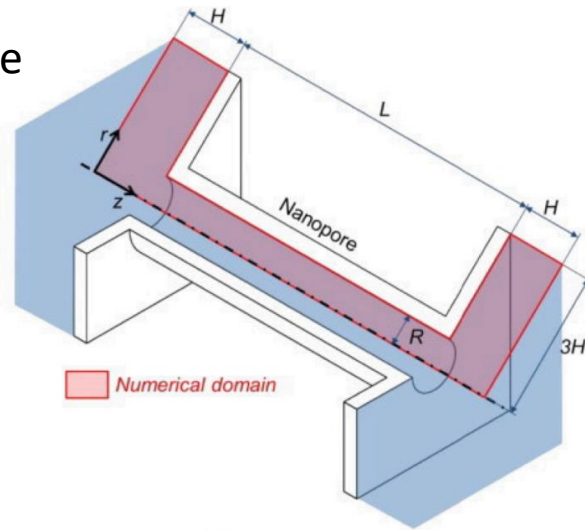
Top view SEM image of PSi



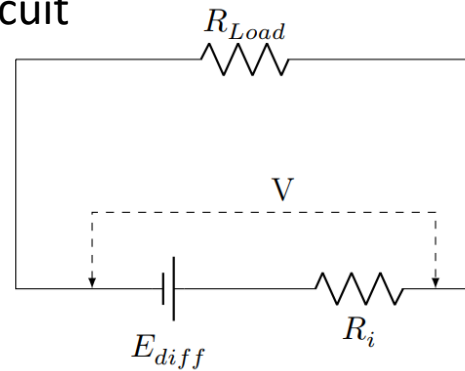
Cross sectional view SEM image of PSi

Simulation model

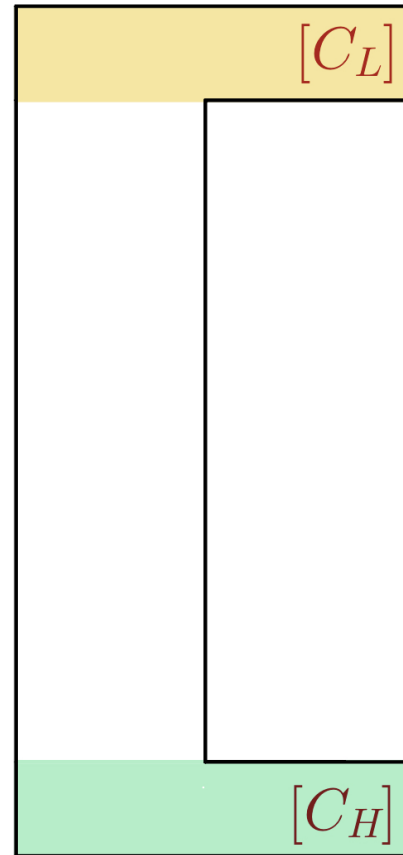
- Domain: 2D half pore



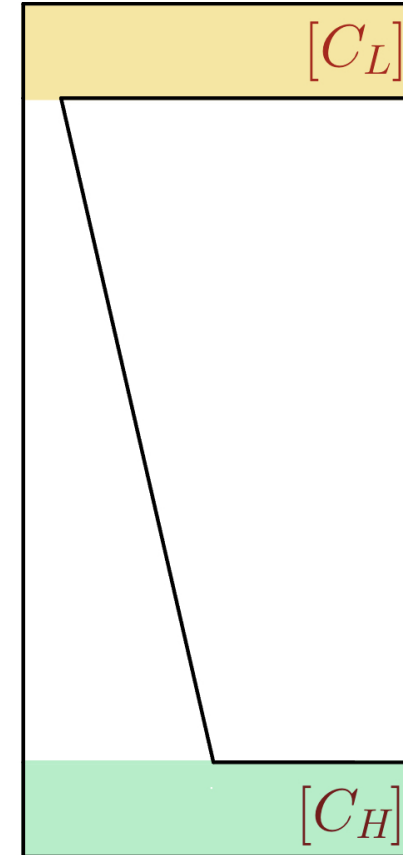
- Equivalent electrical circuit



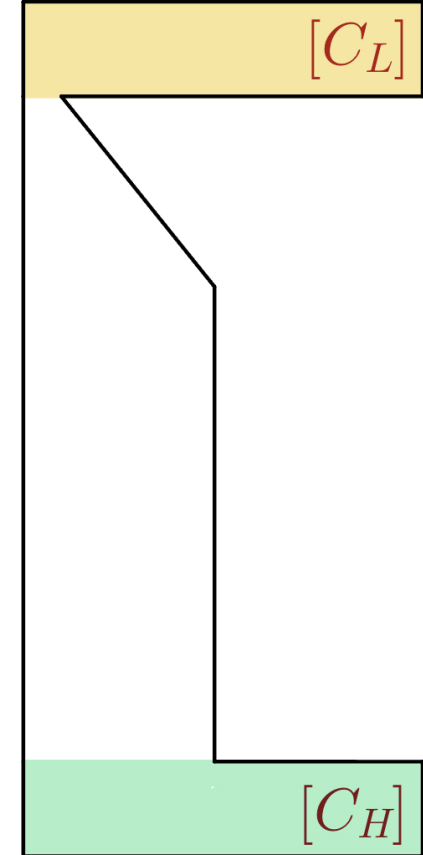
Cylindrical



Conical

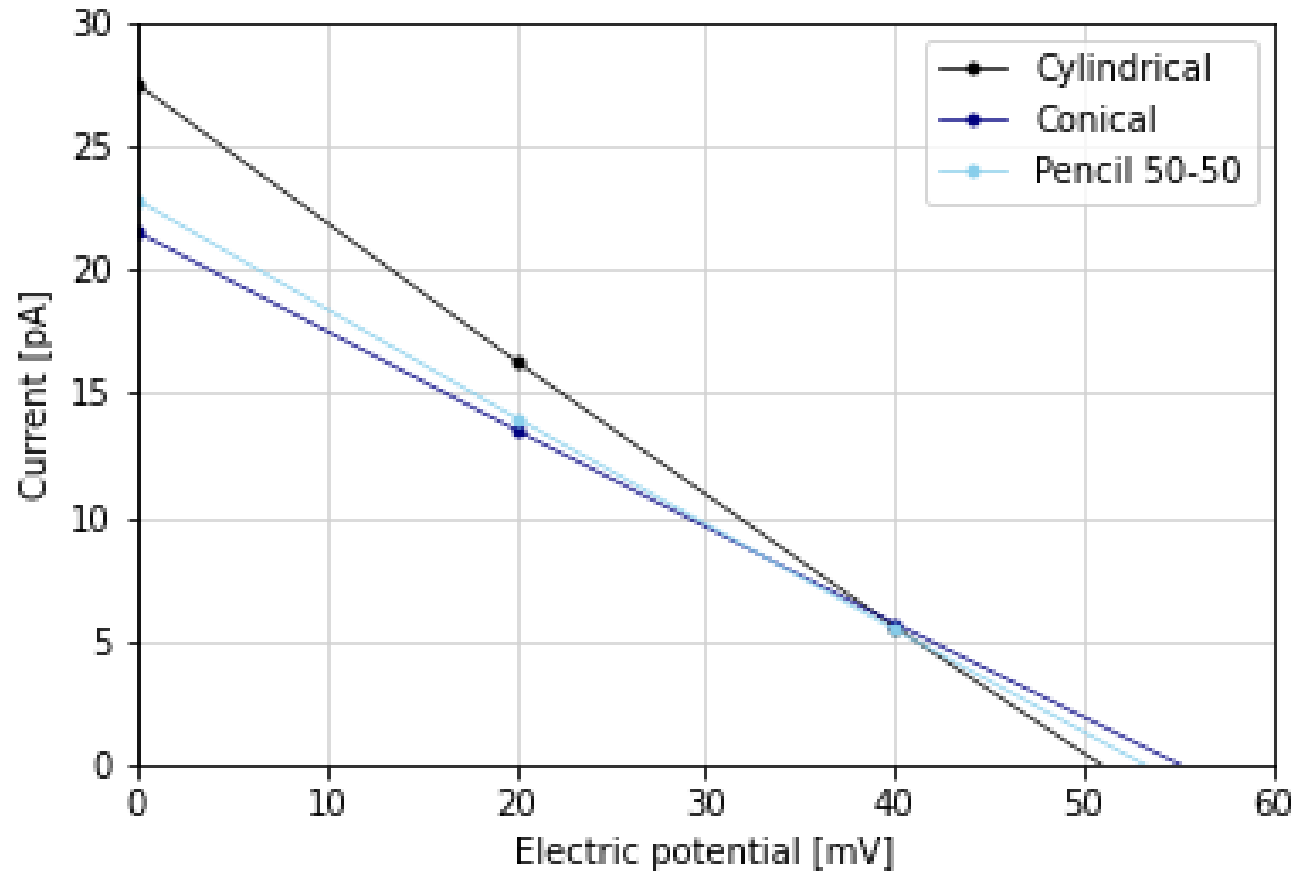


Pencil



Topology impact

- Numerical simulation IV curves for a single pore in different shapes



[CH]=1 mM and [CL]=0.1 mM

trade-off selectivity-current

➤ **PENCIL SHAPE**